

#11/B (NE)  
Hawkins  
12/10/02  
PATENT APPLICATIONRESPONSE UNDER 37 CFR §1.116  
EXPEDITED PROCEDURE  
TECHNOLOGY CENTER ART UNIT 2834

## IN THE UNITED STATES PATENT AND TRADEMARK OFFICE

In re the Application of

Toshinari MURAI et al.

Group Art Unit: 2834

Application No.: 09/865,574

Examiner: M. Budd

Filed: May 29, 2001

Docket No.: 109605

For: PIEZOELECTRIC OXIDE SINGLE CRYSTAL WAFER

AMENDMENT AFTER FINAL REJECTION UNDER 37 CFR §1.116Director of the U.S. Patent and Trademark Office  
Washington, D.C. 20231

Sir:

In reply to the May 15, 2002 Office Action, the period for response being extended by the attached Petition for Extension of Time, please amend the above-identified application as follows:

IN THE CLAIMS:

Please cancel claims 3 and 4 without prejudice to or disclaimer of the subject matter contained therein.

Please replace claim 1 as follows:

1. (Amended) A piezoelectric oxide single crystal wafer, wherein metal electrodes having a width of 1  $\mu\text{m}$  or less are to be formed on a surface of the wafer, and a number of particles adhering to the surface of the wafer and having a size of 1  $\mu\text{m}$  or more is 85 or less per  $\text{mm}^2$ .

REMARKS

Claims 1 and 2 are pending. By this Amendment, claims 3 and 4 are canceled without prejudice or disclaimer, and claim 1 is amended. Reconsideration based on the above amendments and following remarks is respectfully requested.